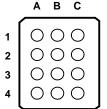
FEATURES

- 1.2 V to 3.6 V on A Port and 1.65 V to 5.5 V on B Port (V_{CCA} ≤ V_{CCB})
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, All Outputs Are in the High-Impedance State
- OE Input Circuit Referenced to V_{CCA}
- Low Power Consumption, 4-μA Max I_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

ESD Protection Exceeds JESD 22

- A Port
 - 2500-V Human-Body Model (A114-B)
 - 200-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)
- B Port
 - ±15-kV Human-Body Model (A114-B)
 - 200-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)

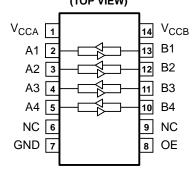
GXU OR ZXU PACKAGE (BOTTOM VIEW)



TERMINAL ASSIGNMENTS (GXU/ZXU Package)

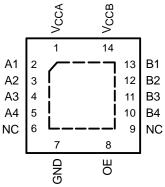
	Α	В	С
1	A1	V _{CCB}	B1
2	A2	V_{CCA}	B2
3	А3	OE	В3
4	A4	GND	B4

D OR PW PACKAGE (TOP VIEW)



NC - No internal connection

RGY PACKAGE (TOP VIEW)



NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

This 4-bit noninverting translator uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes. V_{CCA} should not exceed V_{CCB} .

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state.

The TXB0104 is designed so that the OE input circuit is supplied by V_{CCA}.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

4-BIT BIDIRECTIONAL VOLTAGE-LEVEL TRANSLATOR WITH AUTO DIRECTION SENSING AND ±15-kV ESD PROTECTION



DESCRIPTION/ORDERING INFORMATION (CONTINUED)

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

ORDERING INFORMATION

T _A	PACKAGE(1)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	UFBGA – GXU	Topo and roal	TXB0104GXUR	
	UFBGA – ZXU (Pb-Free)	Tape and reel	TXB0104ZXUR	
-40°C to 85°C	QFN – RGY	Tape and reel	TXB0104RGYR	
	SOIC - D	Tape and reel	TXB0104DR	
	TSSOP – PW Tape and reel		TXB0104PWR	

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

PIN DESCRIPTION

D, PW, OR RGY PIN NO.	GXU OR ZXU BALL NO.	NAME	FUNCTION
1	B2	V _{CCA}	A-port supply voltage 1.2 V \leq V _{CCA} \leq 3.6 V and V _{CCA} \leq V _{CCB} .
2	A1	A1	Input/output 1. Referenced to V _{CCA} .
3	A2	A2	Input/output 2. Referenced to V _{CCA} .
4	A3	A3	Input/output 3. Referenced to V _{CCA} .
5	A4	A4	Input/output 4. Referenced to V _{CCA} .
6		NC	No connection. Not internally connected.
7	B4	GND	Ground
8	В3	OE	3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V _{CCA} .
9		NC	No connection. Not internally connected.
10	C4	B4	Input/output 4. Referenced to V _{CCB} .
11	C3	В3	Input/output 3. Referenced to V _{CCB} .
12	C2	B2	Input/output 2. Referenced to V _{CCB} .
13	C1	B1	Input/output 1. Referenced to V _{CCB} .
14	B1	V _{CCB}	B-port supply voltage 1.65 V \leq V _{CCB} \leq 5.5 V.

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V_{CCA}	Supply veltage range		-0.5	4.6	V	
V_{CCB}	Supply voltage range		-0.5	6.5	V	
V_{I}	Input voltage range (2)		-0.5	6.5	V	
V_{O}	Voltage range applied to any output in the high-impedance or pov	age range applied to any output in the high-impedance or power-off state (2)				
V	Voltage range applied to any output in the high or low state (2)(3)	A port	-0.5	$V_{CCA} + 0.5$	V	
Vo	voltage range applied to any output in the high or low state	B port	-0.5	$V_{CCB} + 0.5$	V	
I _{IK}	Input clamp current	V ₁ < 0		-50		
I_{OK}	Output clamp current	V _O < 0		-50		
Io	Continuous output current					
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA	
		D package ⁽⁴⁾		86		
0	Dealers thermal impedance	GXU/ZXU package (4)		TBD	°C/M	
θ_{JA}	Package thermal impedance	PW package ⁽⁴⁾		113	°C/W	
		RGY package (5)		47		
T _{stg}	Storage temperature range		-65	150	°C	

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 (3) The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.
 (4) The package thermal impedance is calculated in accordance with JESD 51-7.

(5) The package thermal impedance is calculated in accordance with JESD 51-5.

Recommended Operating Conditions (1)(2)

			V _{CCA}	V _{CCB}	MIN	MAX	UNIT
V_{CCA}	Complexedtana				1.2	3.6	V
V_{CCB}	Supply voltage				1.65	5.5	"
V	High lovel input voltage	Data inputs	1.2 V to 3.6 V	1.65 V to 5.5 V	$V_{CCI} \times 0.65^{(3)}$	V _{CCI}	V
V _{IH}	High-level input voltage	OE	1.2 V to 3.6 V	1.65 V to 5.5 V	V _{CCA} × 0.65	5.5	'
V	Low lovel input voltage	Data inputs	1.2 V to 5.5 V	1.65 V to 5.5 V	0	$V_{CCI} \times 0.35^{(3)}$	V
V _{IL}	Low-level input voltage	OE	1.2 V to 3.6 V	1.65 V to 5.5 V	0	V _{CCA} × 0.35	"
		A-port inputs	1.2 V to 3.6 V	1.65 V to 5.5 V		40	
Δt/Δν	Input transition rise or fall rate	P port inpute	1.2 V to 3.6 V	1.65 V to 3.6 V		40	ns/V
	noc or rail rate	B-port inputs	1.2 V 10 3.6 V	4.5 V to 5.5 V		30	
T _A	Operating free-air temperat	ure			-40	85	°C

⁽¹⁾ The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V_{CCI} or both at GND.

(2) V_{CCA} must be less than or equal to V_{CCB} and must not exceed 3.6 V.
 (3) V_{CCI} is the supply voltage associated with the input port.

TXB0104

4-BIT BIDIRECTIONAL VOLTAGE-LEVEL TRANSLATOR WITH AUTO DIRECTION SENSING AND ±15-kV ESD PROTECTION



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Electrical Characteristics (1)(2)

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST	V	V	T,	_A = 25°C	,	-40°C to 8	85°C	UNIT
	PARAIVIETER	CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNII
\/		J 20 A	1.2 V			1.1				V
V _{OHA}		$I_{OH} = -20 \mu A$	1.4 V to 3.6 V					V _{CCA} - 0.4		V
\/		J 20 A	1.2 V			0.9				V
V_{OLA}		$I_{OL} = 20 \mu A$	1.4 V to 3.6 V						0.4	V
V_{OHB}		$I_{OH} = -20 \mu A$		1.65 V to 5.5 V				V _{CCB} - 0.4		V
V_{OLB}		$I_{OL} = 20 \mu A$		1.65 V to 5.5 V					0.4	V
I _I	OE		1.2 V to 3.6 V	1.65 V to 5.5 V			±1		±2	μА
	A port		0 V	0 V to 5.5 V			±1		±2	
I _{off}	B port		0 V to 3.6 V	0 V			±1		±2	μА
I _{OZ}	A or B port	OE = GND	1.2 V to 3.6 V	1.65 V to 5.5 V			±1		±2	μА
			1.2 V	1.65 V to 5.5 V		0.06				
		$V_I = V_{CCI}$ or GND,	1.4 V to 3.6 V	1.65 V to 5.5 V					5	
I _{CCA}		$I_{O} = 0$	3.6 V	0 V					2	μA
			0 V	5.5 V					-2	
			1.2 V	1.65 V to 5.5 V		3.4				
		$V_I = V_{CCI}$ or GND,	1.4 V to 3.6 V	1.65 V to 5.5 V					5	
I _{CCB}		$I_{O} = 0$	3.6 V	0 V					-2	μA
			0 V	5.5 V					2	
		$V_I = V_{CCI}$ or GND,	1.2 V	1.65 V to 5.5 V		3.5				
I _{CCA} +	CCB	$I_{O} = 0$	1.4 V to 3.6 V	1.65 V to 5.5 V					10	μA
		$V_I = V_{CCI}$ or GND,	1.2 V	1.65 V to 5.5 V		0.05				
I _{CCZA}		I _O = 0, OE = GND	1.4 V to 3.6 V	1.65 V to 5.5 V					5	μΑ
		$V_I = V_{CCI}$ or GND,	1.2 V	1.65 V to 5.5 V		3.3				
I _{CCZB}		$I_O = 0$, OE = GND	1.4 V to 3.6 V	1.65 V to 5.5 V					5	μΑ
Ci	OE		1.2 V to 3.6 V	1.65 V to 5.5 V		3			4	pF
C	A port		1.2 V to 3.6 V	1.65 V to 5.5 V		5			6	nE.
C _{io}	B port		1.2 V 10 3.0 V	1.00 V 10 0.0 V		11			14	pF

Timing Requirements

$$T_A = 25$$
°C, $V_{CCA} = 1.2 \text{ V}$

			V _{CCB} = 1.8 V	$V_{CCB} = 2.5 V$	$V_{CCB} = 3.3 \text{ V}$	$V_{CCB} = 5 V$	UNIT
			TYP	TYP	TYP	TYP	ONIT
	Data rate		20	20	20	20	Mbps
t_{w}	Pulse duration	Data inputs	50	50	50	50	ns

Timing Requirements

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

			V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate			40		40		40		40	Mbps
t _w	Pulse duration	Data inputs	25		25		25		25		ns

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCI} \text{ is the supply voltage associated with the input port.} \\ \hbox{(2)} & V_{CCO} \text{ is the supply voltage associated with the output port.} \\ \end{array}$

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Timing Requirements

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

					V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate			60		60		60		60	Mbps
t _w	Pulse duration	Data inputs	17		17		17		17		ns

Timing Requirements

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

			V _{CCB} = ± 0.2		V _{CCB} = 3 ± 0.3			V _{CCB} = 5 V ± 0.5 V	
			MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate			100		100		100	Mbps
t _w	Pulse duration	Data inputs	10		10		10		ns

Timing Requirements

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

			V _{CCB} = 3 ± 0.3	.3 V V	V _{CCB} = 5 ± 0.5 V	V _{CCB} = 5 V ± 0.5 V	
			MIN	MAX	MIN	MAX	
	Data rate			100		100	Mbps
t _w	Pulse duration	Data inputs	10		10		ns

Switching Characteristics

 $T_A = 25^{\circ}C, V_{CCA} = 1.2 V$

PARAMETER	FROM	то	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	V _{CCB} = 5 V	UNIT
PARAMETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP 5.5 5.8 1 1 1 4 16 4.2	UNIT
	Α	В	6.9	5.7	5.3	5.5	20
t _{pd}	В	Α	7.4	6.4	6	5.8	ns
	OF	A	1	1	1	1	
t _{en}	OE	В	1	1	1	1	μs
	OE	Α	18	15	14	14	20
t _{dis}	OE .	В	20	17	16	16	ns
t _{rA} , t _{fA}	A-port rise a	nd fall times	4.2	4.2	4.2	4.2	ns
t _{rB} , t _{fB}	B-port rise a	nd fall times	2.1	1.5	1.2	1.1	ns
t _{SK(O)}	Channel-to-c	channel skew	0.4	0.5	0.5	1.4	ns
Max data rate			20	20	20	20	Mbps



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Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		V _{CCB} = ± 0.	= 5 V 5 V	UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Α	В	1.4	12.9	1.2	10.1	1.1	10	0.8	9.9	20
t _{pd}	В	Α	0.9	14.2	0.7	12	0.4	11.7	0.3	13.7	ns
4	OE	Α		1		1		1		1	
t _{en}	OE	В		1		1		1		1	μs
	OE	Α	5.9	31	5.7	25.9	5.6	23	5.7	22.4	ns
t _{dis}	OE	В	5.4	30.3	4.9	22.8	4.8	20	4.9	19.5	
t _{rA} , t _{fA}	A-port rise a	nd fall times	1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
t _{rB} , t _{fB}	B-port rise a	and fall times	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t _{SK(O)}	Channel-to-c	channel skew		0.5		0.5		0.5		0.5	ns
Max data rate		_	40		40		40		40		Mbps

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		V _{CCB} = ± 0.5	= 5 V 5 V	UNIT
	(INFOT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MIN MAX	
4	Α	В	1.6	11	1.4	7.7	1.3	6.8	1.2	6.5	2
t _{pd}	В	Α	1.5	12	1.3	8.4	8.4 1 7.6 0.9	7.1	ns		
	0.5	Α		1		1		1		1	
t _{en}	OE	В		1		1		1		1	μs
	OE	Α	5.9	31	5.1	21.3	5	19.3	5	17.4	ns
t _{dis}	OE	В	5.4	30.3	4.4	20.8	4.2	17.9	4.3	16.3	
t _{rA} , t _{fA}	A-port rise a	and fall times	1	4.2	1.1	4.1	1.1	4.1	1.1	4.1	ns
t _{rB} , t _{fB}	B-port rise a	and fall times	0.9	3.8	0.6	3.2	0.5	2.8	0.4	2.7	ns
t _{SK(O)}	Channel-to-c	channel skew		0.5		0.5		0.5		0.5	ns
Max data rate			60		60		60		60		Mbps

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Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM	TO (OUTPUT)		V _{CCB} = 2.5 V ± 0.2 V				3.3 V V	V _{CCB} = 5 V ± 0.5 V		UNIT
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX			
	А	В	1.1	6.3	1	5.2	0.9	4.7	20		
t _{pd}	В	Α	1.2	6.6	1.1	5.1	0.9	4.4	ns		
	OE	Α		1		1		1	μs		
t _{en}	OE	В		1		1		1			
	05	Α	5.1	21.3	4.6	15.2	4.6	13.2			
t _{dis}	OE	В	4.4	20.8	3.8	16	3.9	13.9	ns		
t _{rA} , t _{fA}	A-port rise a	and fall times	0.8	3	0.8	3	0.8	3	ns		
t _{rB} , t _{fB}	B-port rise a	and fall times	0.7	2.6	0.5	2.8	0.4	2.7	ns		
t _{SK(O)}	Channel-to-c	channel skew		0.5		0.5		0.5	ns		
Max data rate			100		100		100		Mbps		

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = 3 ± 0 .3	V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V	
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	
	А	В	0.9	4.7	0.8	4	no
t _{pd}	В	A	1	4.9	0.9	3.8	ns
	٥٢	A		1		1	μs
t _{en}	OE	В		1		1	
	OF	A	4.6	15.2	4.3	12.1	
t _{dis}	OE	В	3.8	16	3.4	13.2	ns
t _{rA} , t _{fA}	A-port rise a	and fall times	0.7	2.5	0.7	2.5	ns
t _{rB} , t _{fB}	B-port rise and fall times		0.5	2.1	0.4	2.7	ns
t _{SK(O)}	Channel-to-c	channel skew		0.5		0.5	ns
Max data rate			100		100		Mbps



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Operating Characteristics

 $T_A = 25^{\circ}C$

			V _{CCA}								
			1.2 V	1.2 V	1.5 V	1.8 V	2.5 V	2.5 V	3.3 V		
			V _{CCB}								
	PARAMETER	TEST CONDITIONS	5 V	5 V 1.8 V 1.8 V		1.8 V	2.5 V	5 V	3.3 V to 5 V	UNIT	
			TYP	TYP	TYP	TYP	TYP	TYP	TYP		
C	A-port input, B-port output	$\begin{aligned} C_L &= 0, f = 10 \text{ MHz}, \\ t_r &= t_f = 1 \text{ ns}, \\ OE &= V_{CCA} \\ \text{(outputs enabled)} \end{aligned}$	7.8	10	9	8	8	8	9	pF	
C_{pdA}	B-port input, A-port output		12	11	11	11	11	11	11		
_	A-port input, B-port output		38.1	28	28	28	29	29	29		
C_{pdB}	B-port input, A-port output		25.4	19	18	18	19	21	22		
C	A-port input, B-port output	C = 0 f = 10 MHz	0.01	0.01	0.01	0.01	0.01	0.01	0.01		
C _{pdA}	B-port input, A-port output	$C_L = 0$, $f = 10 \text{ MHz}$, $t_r = t_f = 1 \text{ ns}$,	0.01	0.01	0.01	0.01	0.01	0.01	0.01	-	
C	A-port input, B-port output	OE = GND	0.01	0.01	0.01	0.01	0.01	0.01	0.03		
C_{pdB}	B-port input, A-port output	(outputs disabled)	0.01	0.01	0.01	0.01	0.01	0.01	0.04		

TXB0104

PRINCIPLES OF OPERATION

Applications

The TXB0104 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

Architecture

The TXB0104 architecture (see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a dc state, the output drivers of the TXB0104 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction.

The output one shots detect rising or falling edges on the A or B ports. During a rising edge, the one shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition.

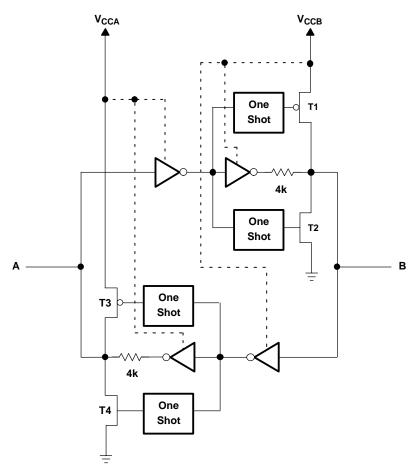


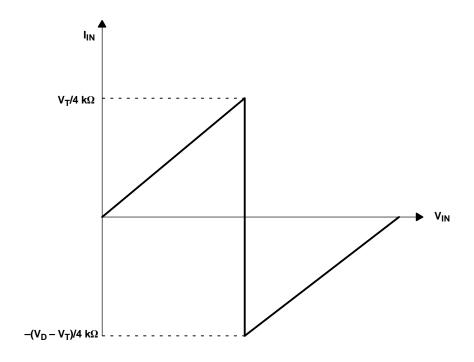
Figure 1. Architecture of TXB0104 I/O Cell

Input Driver Requirements

Typical I_{IN} vs V_{IN} characteristics of the TXB0104 are shown in Figure 2. For proper operation, the device driving the data I/Os of the TXB0104 must have drive strength of at least ±2 mA.



PRINCIPLES OF OPERATION (continued)



- A. V_T is the input threshold voltage of the TXB0104 (typically $V_{CCI}/2$).
- B. V_D is the supply voltage of the external driver.

Figure 2. Typical $I_{\rm IN}$ vs $V_{\rm IN}$ Curve

Power Up

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \ge V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The TXB0104 has circuitry that disables all output ports when either V_{CC} is switched off $(V_{CCA/B} = 0 \text{ V})$.

Enable and Disable

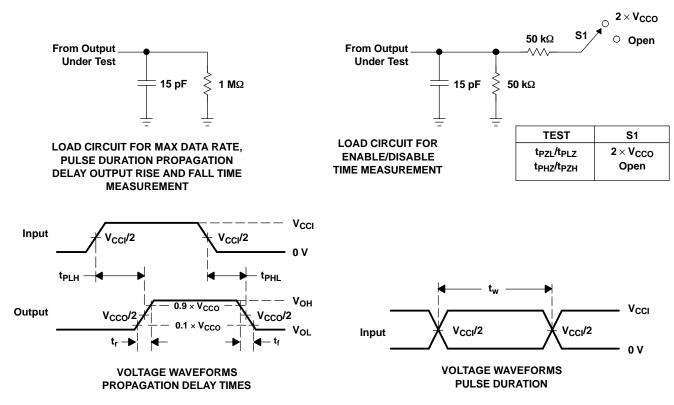
The TXB0104 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (t_{dis}) indicates the delay between when OE goes low and when the outputs acutally get disabled (Hi-Z). The enable time (ten) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Pullup or Pulldown Resistors on I/O Lines

The TXB0104 is designed to drive capacitive loads of up to 70 pF. The output drivers of the TXB0104 have low dc drive strength. If pullup or pulldown resistors are connected externally to the data I/Os, their values must be kept higher than 50 k Ω to ensure that they do not contend with the output drivers of the TXB0104.

For the same reason, the TXB0104 should not be used in applications such as I²C, 1-Wire, or an MMC card interface where an open-drain driver is connected on the bidirectional data I/O. For these applications, use a device from the TI TXS01xx series of level translators.

PARAMETER MEASUREMENT INFORMATION



- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \ \Omega$, $dv/dt \geq 1 \ V/ns$.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd}.
- E. V_{CCI} is the V_{CC} associated with the input port.
- F. V_{CCO} is the V_{CC} associated with the output port.
- G. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuits and Voltage Waveforms

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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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